

FEATURES

Voltage noise density: 2.8 nV/ $\sqrt{\text{Hz}}$ typical

Peak-to-peak noise: 77 nV p-p typical

Gain bandwidth product: 10 MHz

Low input bias current: 14 nA maximum

Low offset voltage: 75 μV maximum

High open-loop gain: 1000 V/mV (120 dB)

Low supply current per amplifier: 3 mA typical

Dual-supply operation: $\pm 5\text{ V}$ to $\pm 15\text{ V}$

Unity-gain stable

No phase reversal

ENHANCED PRODUCT FEATURES

Supports defense and aerospace applications (AQEC standard)

Extended temperature range: -55°C to $+125^\circ\text{C}$

Controlled manufacturing baseline

One assembly/test site

One fabrication site

Enhanced product change notification

Qualification data available on request

APPLICATIONS

Phase-locked loop (PLL) filters

Filters for GPS

Instrumentation

Sensors and controls

Professional quality audio

PIN CONFIGURATION

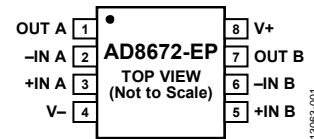


Figure 1.

GENERAL DESCRIPTION

The **AD8672-EP** is a very high precision amplifier featuring very low noise, very low offset voltage and drift, low input bias current, 10 MHz bandwidth, and low power consumption. Outputs are stable with capacitive loads of over 1000 pF. Supply current is less than 3 mA per amplifier at 30 V.

The combination of ultralow noise, high precision, speed, and stability within the **AD8672-EP** is unmatched. Applications for this amplifier include high quality PLL filters, precision filters, medical and analytical instrumentation, precision power supply controls, ATE, data acquisition, and precision controls, as well as professional quality audio.

The **AD8672-EP** is available in an 8-lead SOIC narrow package. It is specified over a -55°C to $+125^\circ\text{C}$ temperature range.

Additional application and technical information can be found in the **AD8672** data sheet.

TABLE OF CONTENTS

| | | | |
|---|---|--|---|
| Features | 1 | Electrical Characteristics, ± 15 V | 4 |
| Enhanced Product Features | 1 | Absolute Maximum Ratings | 5 |
| Applications..... | 1 | Thermal Resistance | 5 |
| Pin Configuration..... | 1 | ESD Caution..... | 5 |
| General Description | 1 | Typical Performance Characteristics | 6 |
| Revision History | 2 | Outline Dimensions | 8 |
| Specifications..... | 3 | Ordering Guide | 8 |
| Electrical Characteristics, ± 5 V | 3 | | |

REVISION HISTORY

9/15—Revision 0: Initial Version

SPECIFICATIONS

ELECTRICAL CHARACTERISTICS, ± 5 V

$V_{SY} = \pm 5.0$ V, $V_{CM} = 0$ V, $T_A = 25^\circ\text{C}$, unless otherwise specified.

Table 1.

| Parameter | Symbol | Test Conditions/Comments | Min | Typ | Max | Unit |
|-------------------------------|--------------------------|--|------|----------|------|------------------------------|
| INPUT CHARACTERISTICS | | | | | | |
| Offset Voltage | V_{OS} | $-55^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 20 | 75 | μV |
| Offset Voltage Drift | $\Delta V_{OS}/\Delta T$ | $-55^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 30 | 125 | $\mu\text{V}/^\circ\text{C}$ |
| Input Bias Current | I_B | $25^\circ\text{C} < T_A < 125^\circ\text{C}$ | -14 | +3 | +14 | nA |
| | | $-55^\circ\text{C} < T_A < +125^\circ\text{C}$ | -20 | +5 | +20 | nA |
| Input Offset Current | I_{OS} | $25^\circ\text{C} < T_A < 125^\circ\text{C}$ | -60 | +8 | +60 | nA |
| | | $-55^\circ\text{C} < T_A < +125^\circ\text{C}$ | -14 | +6 | +14 | nA |
| | | $25^\circ\text{C} < T_A < 125^\circ\text{C}$ | -20 | +6 | +20 | nA |
| | | $-55^\circ\text{C} < T_A < +125^\circ\text{C}$ | -60 | +8 | +60 | nA |
| Input Voltage Range | | | -2.5 | | +2.5 | V |
| Common-Mode Rejection Ratio | CMRR | $V_{CM} = -2.5$ V to $+2.5$ V | 100 | 120 | | dB |
| Large Signal Voltage Gain | A_{VO} | $R_L = 2$ k Ω , $V_O = -3$ V to $+3$ V | 1000 | 6000 | | V/mV |
| Input Capacitance | | | | | | |
| Common Mode | C_{INCM} | | | 6.25 | | pF |
| Differential Mode | C_{INDM} | | | 7.5 | | pF |
| Input Resistance | | | | | | |
| Common Mode | R_{IN} | | | 3.5 | | G Ω |
| Differential Mode | R_{INDM} | | | 15 | | M Ω |
| OUTPUT CHARACTERISTICS | | | | | | |
| Output Voltage | | | | | | |
| High | V_{OH} | $R_L = 2$ k Ω , -55°C to $+125^\circ\text{C}$ | +3.8 | +4.0 | | V |
| | | $R_L = 600$ Ω | +3.7 | +3.9 | | V |
| Low | V_{OL} | $R_L = 2$ k Ω , -55°C to $+125^\circ\text{C}$ | | -3.9 | -3.8 | V |
| | | $R_L = 600$ Ω | | -3.8 | -3.7 | V |
| Output Current | I_{OUT} | | | ± 10 | | mA |
| POWER SUPPLY | | | | | | |
| Power Supply Rejection Ratio | PSRR | $V_S = \pm 4$ V to ± 18 V | 110 | 130 | | dB |
| Supply Current per Amplifier | I_{SY} | $V_O = 0$ V $-55^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 3 | 3.5 | mA |
| | | | | | 4.2 | mA |
| DYNAMIC PERFORMANCE | | | | | | |
| Slew Rate | SR | $R_L = 2$ k Ω | | 4 | | V/ μs |
| Settling Time | t_S | To 0.1% (4 V step, $G = 1$) | | 1.4 | | μs |
| | | To 0.01% (4 V step, $G = 1$) | | 5.1 | | μs |
| Gain Bandwidth Product | GBP | | | 10 | | MHz |
| NOISE PERFORMANCE | | | | | | |
| Peak-to-Peak Noise | $e_{n\text{ p-p}}$ | 0.1 Hz to 10 Hz | | 77 | 100 | nV p-p |
| Voltage Noise Density | e_n | $f = 1$ kHz | | 2.8 | 3.8 | nV/ $\sqrt{\text{Hz}}$ |
| Current Noise Density | i_n | $f = 1$ kHz | | 0.3 | | pA/ $\sqrt{\text{Hz}}$ |
| Channel Separation | C_S | $f = 1$ kHz | | -130 | | dB |
| | | $f = 10$ kHz | | -105 | | dB |

ELECTRICAL CHARACTERISTICS, ± 15 V

$V_S = \pm 15.0$ V, $V_{CM} = 0$ V, $T_A = 25^\circ\text{C}$, unless otherwise specified.

Table 2.

| Parameter | Symbol | Test Conditions/Comments | Min | Typ | Max | Unit |
|-------------------------------|--------------------------|--|------|----------|-------|------------------------------|
| INPUT CHARACTERISTICS | | | | | | |
| Offset Voltage | V_{OS} | $-55^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 20 | 75 | μV |
| Offset Voltage Drift | $\Delta V_{OS}/\Delta T$ | $-55^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 30 | 125 | $\mu\text{V}/^\circ\text{C}$ |
| Input Bias Current | I_B | $25^\circ\text{C} < T_A < 125^\circ\text{C}$ | -14 | +3 | +14 | nA |
| | | $-55^\circ\text{C} < T_A < +125^\circ\text{C}$ | -20 | +5 | +20 | nA |
| Input Offset Current | I_{OS} | $25^\circ\text{C} < T_A < 125^\circ\text{C}$ | -60 | +8 | +60 | nA |
| | | $-55^\circ\text{C} < T_A < +125^\circ\text{C}$ | -14 | +6 | +14 | nA |
| | | $25^\circ\text{C} < T_A < 125^\circ\text{C}$ | -20 | +6 | +20 | nA |
| | | $-55^\circ\text{C} < T_A < +125^\circ\text{C}$ | -60 | +8 | +60 | nA |
| Input Voltage Range | | | -12 | | +12 | V |
| Common-Mode Rejection Ratio | CMRR | $V_{CM} = -12$ V to +12 V | 100 | 120 | | dB |
| Large Signal Voltage Gain | A_{VO} | $R_L = 2$ k Ω , $V_O = -10$ V to +10 V | 1000 | 6000 | | V/mV |
| Input Capacitance | | | | | | |
| Common Mode | C_{INCM} | | | 6.25 | | pF |
| Differential Mode | C_{INDM} | | | 7.5 | | pF |
| Input Resistance | | | | | | |
| Common Mode | R_{IN} | | | 3.5 | | G Ω |
| Differential Mode | R_{INDM} | | | 15 | | M Ω |
| OUTPUT CHARACTERISTICS | | | | | | |
| Output Voltage | | | | | | |
| High | V_{OH} | $R_L = 2$ k Ω , -55°C to $+125^\circ\text{C}$ | 13.2 | 13.8 | | V |
| | | $R_L = 600$ Ω | 11 | 12.3 | | V |
| Low | V_{OL} | $R_L = 2$ k Ω , -55°C to $+125^\circ\text{C}$ | | -13.8 | -13.2 | V |
| | | $R_L = 600$ Ω | | -12.4 | -11 | V |
| Output Current | I_{OUT} | | | ± 20 | | mA |
| Short Circuit Current | I_{SC} | | | ± 30 | | mA |
| POWER SUPPLY | | | | | | |
| Power Supply Rejection Ratio | PSRR | $V_S = \pm 4$ V to ± 18 V | 110 | 130 | | dB |
| Supply Current per Amplifier | I_{SY} | $V_O = 0$ V $-55^\circ\text{C} < T_A < +125^\circ\text{C}$ | | 3 | 3.5 | mA |
| | | | | | 4.2 | mA |
| DYNAMIC PERFORMANCE | | | | | | |
| Slew Rate | SR | $R_L = 2$ k Ω | | 4 | | V/ μs |
| Settling Time | t_s | To 0.1% (10 V step, G = 1) | | 2.2 | | μs |
| | | To 0.01% (10 V step, G = 1) | | 6.3 | | μs |
| Gain Bandwidth Product | GBP | | | 10 | | MHz |
| NOISE PERFORMANCE | | | | | | |
| Peak-to-Peak Noise | $e_{n\text{ p-p}}$ | 0.1 Hz to 10 Hz | | 77 | 100 | nV p-p |
| Voltage Noise Density | e_n | $f = 1$ kHz | | 2.8 | 3.8 | nV/ $\sqrt{\text{Hz}}$ |
| Current Noise Density | i_n | $f = 1$ kHz | | 0.3 | | pA/ $\sqrt{\text{Hz}}$ |
| Channel Separation | C_S | $f = 1$ kHz | | -130 | | dB |
| | | $f = 10$ kHz | | -105 | | dB |

ABSOLUTE MAXIMUM RATINGS

Table 3.

| Parameter | Rating |
|--|---|
| Supply Voltage | 36 V |
| Input Voltage | V_{S-} to V_{S+} |
| Differential Input Voltage | ± 0.7 V |
| Output Short-Circuit Duration | Indefinite |
| Storage Temperature Range | -65°C to $+150^{\circ}\text{C}$ |
| Operating Temperature Range | -55°C to $+125^{\circ}\text{C}$ |
| Junction Temperature Range | -65°C to $+150^{\circ}\text{C}$ |
| Lead Temperature Range (Soldering, 60 sec) | 300°C |

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

THERMAL RESISTANCE

θ_{JA} is specified for the worst-case conditions, that is, θ_{JA} is specified for the device soldered on a 4-layer circuit board for surface-mount packages.

Table 4.

| Package Type | θ_{JA} | θ_{JC} | Unit |
|---------------------|---------------|---------------|-----------------------------|
| 8-Lead SOIC_N (R-8) | 120 | 43 | $^{\circ}\text{C}/\text{W}$ |

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

TYPICAL PERFORMANCE CHARACTERISTICS

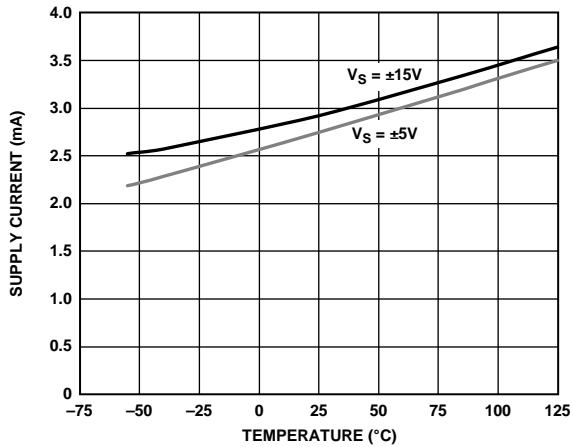


Figure 2. Supply Current vs. Temperature

13063-101

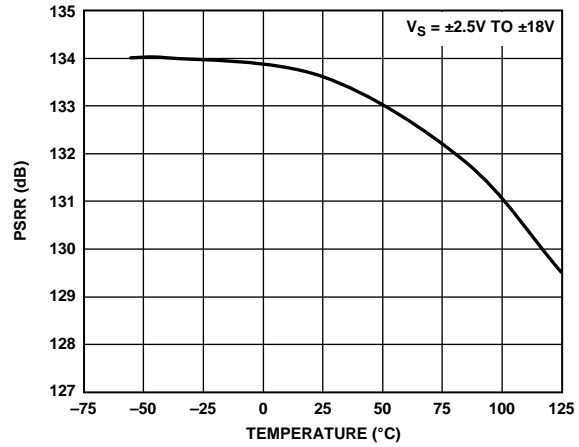


Figure 5. PSRR vs. Temperature

13063-104

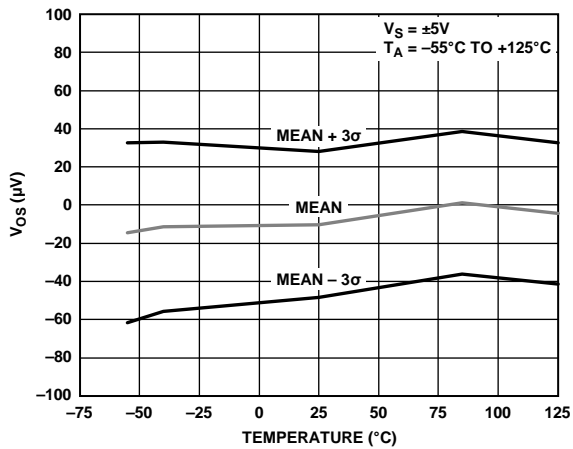


Figure 3. Input Offset Voltage (V_{OS}) vs. Temperature, $V_S = \pm 5V$

13063-102

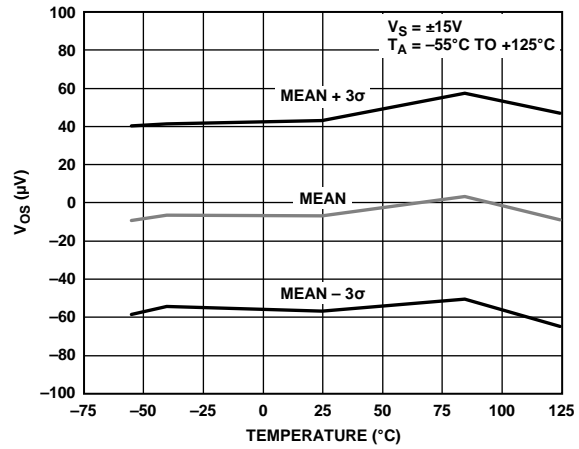


Figure 6. Input Offset Voltage (V_{OS}) vs. Temperature, $V_S = \pm 15V$

13063-105

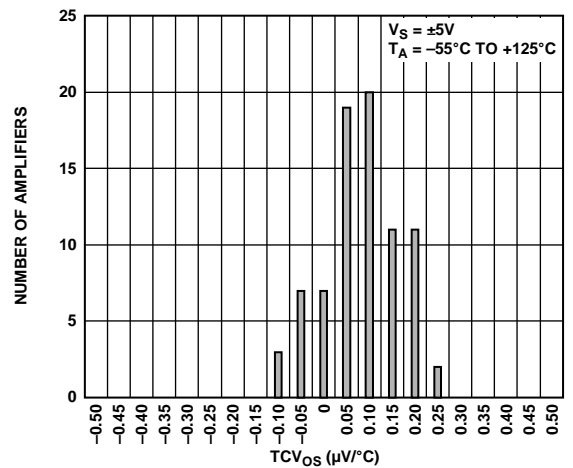


Figure 4. Input Offset Voltage Drift (TCV_{OS}) Distribution, $V_S = \pm 5V$

13063-103

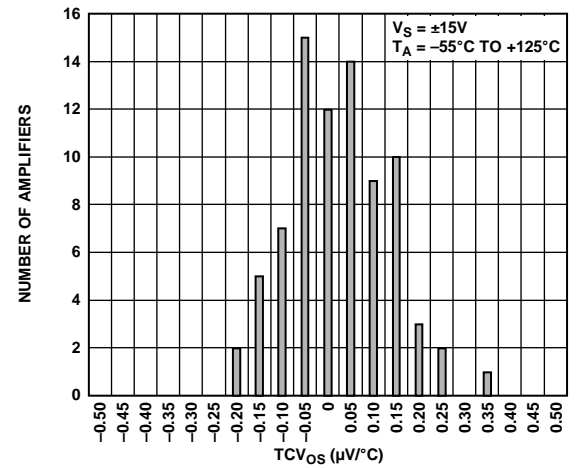


Figure 7. Input Offset Voltage Drift (TCV_{OS}) Distribution, $V_S = \pm 15V$

13063-106



Figure 8. Input Bias Current (I_B) vs. Temperature, $V_S = \pm 5V$

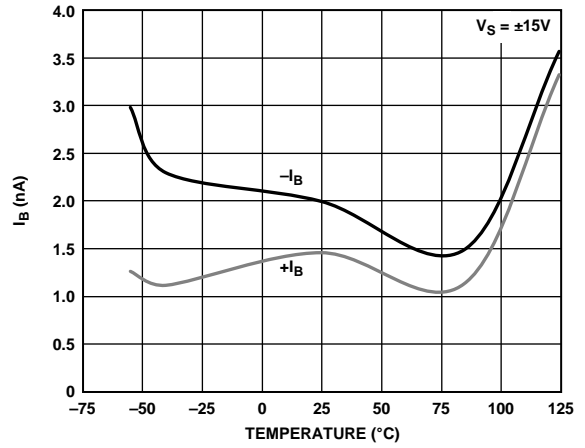


Figure 11. Input Bias Current (I_B) vs. Temperature, $V_S = \pm 15V$

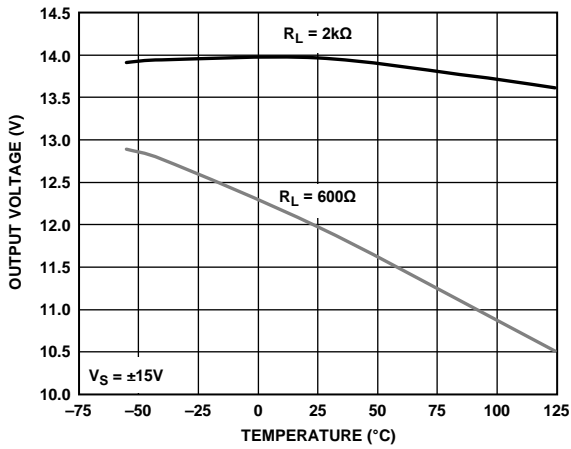


Figure 9. Output Voltage High vs. Temperature

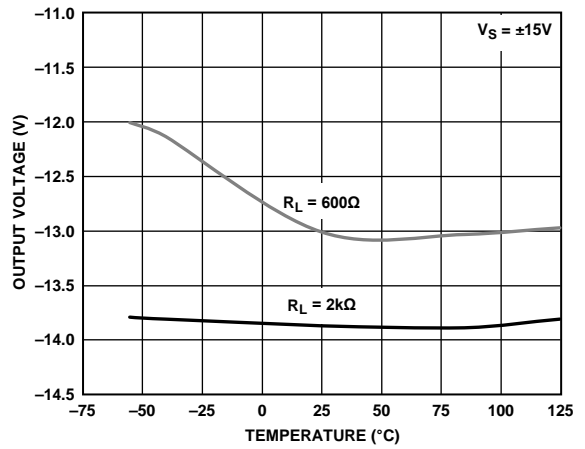


Figure 12. Output Voltage Low vs. Temperature

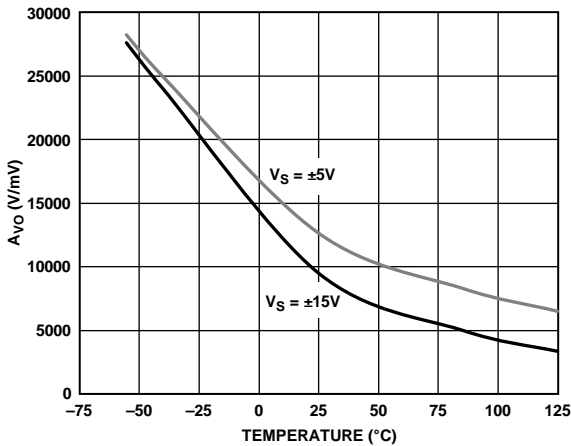


Figure 10. Open-Loop Gain (A_{vo}) vs. Temperature

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MS-012-AA
 CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
 (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
 REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 13. 8-Lead Standard Small Outline Package [SOIC_N]
 Narrow Body (R-8)
 Dimensions shown in millimeters and (inches)

012407-A

ORDERING GUIDE

| Model ¹ | Temperature Range | Package Description | Package Option |
|--------------------|-------------------|--|----------------|
| AD8672TRZ-EP | -55°C to +125°C | 8-Lead Standard Small Outline Package [SOIC_N] | R-8 |
| AD8672TRZ-EP-R7 | -55°C to +125°C | 8-Lead Standard Small Outline Package [SOIC_N] | R-8 |

¹ Z = RoHS Compliant Part.

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)

Email: org@lifeelectronics.ru